Wuxi Unigroup Microelectronics CO.,LTD.

68V N-Channel Trench MOSFET(Preliminary)

General Description

- Trench Power Technology
- Low $R_{DS(ON)}$
- Low Gate Charge
- Optimized for Fast-switching Applications`

Applications

- Synchronous Rectification in DC/DC and AC/DC Converters
- Isolated DC/DC Converters in Telecom and Industrial

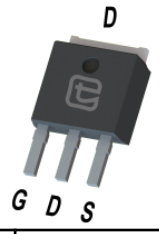
Product Summary

V_{DS}	68V
I_D (at V_{GS}=10V)	95A
$R_{DS(ON)}$ (at V_{GS}=10V)	< 7.5mΩ

100% UIS Tested

RoHS

TO-251



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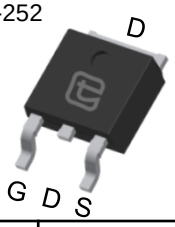
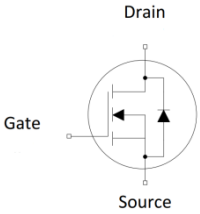




Device	Package	Form	Marking
TTD95N68A	TO-252	Tape&Reel	95N68A
TTU95N68A	TO-251	Tape&Reel	95N68A

Absolute Maximum Ratings (T_A =25ºC unless otherwise noted)

Parameter		Symbol	Maximum	Units
Drain-Source Voltage		V_{DS}	68	V
Gate-Source Voltage		V_{GS}	±20	V
Continuous Drain Current	T_C = 25ºC	I_D	46	A
	T_C = 100ºC		46	
Pulsed Drain Current [A]		I_{DM}	285	A
Avalanche Current [A]		I_{AS}	37	A
Single Pulse Avalanche Energy L =0.3mH [A]		E_{AS}	380	mJ
Power Dissipation [C]	T_C = 25ºC	P_D	130.5	W
	T_C = 100ºC		65.5	W
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55 to 175	ºC

Thermal Characteristics

Parameter		Symbol	Maximum	Units
Maximum Junction-to-Case	Steady-State	R_{thJC}	1.15	ºC/W
Maximum Junction-to-Ambient	Steady-State	R_{thJA}	100	

Electrical Characteristics(T_J =25ºC unless otherwise noted)							
Symbol	**Parameter**	**Conditions**		**Value**			**Units**
				Min	**Typ**	**Max**	
STATIC PARAMETERS							
BV_{DSS}	Drain-Source Breakdown Voltage	I_D =250μA,V_{GS} =0V		68	--	--	V
I_{DSS}	Zero Gate Voltage Drain Current	V_{DS} =68V, V_{GS} =0V	T_J =25ºC	--	--	1	μA
			T_J =100ºC	--	--	25	
I_{GSS}	Gate-Body Leakage Current	V_{DS} =0V, V_{GS} =±20V		--	--	±100	nA
$V_{GS(th)}$	Gate Threshold Voltage	V_{DS} =V_{GS}, I_D =250μA		2	3	4	V
$R_{DS(ON)}$	Static Drain-Source On-Resistance	V_{GS} =10V, I_D =30A		--	6.5	7.5	mΩ
g_{FS}	Forward Transconductance	V_{DS} = 5V, I_D =20A		--	30	--	S
V_{SD}	Diode Forward Voltage	I_S =20A, V_{GS} =0V		--	--	1	V
I_S	Maximum Body-Diode Continuous Current [B]			--	--	46	A
DYNAMIC PARAMETERS							
C_{iss}	Input Capacitance	V_{GS} =0V, V_{DS} =30V, f =1MH_Z		--	4169	--	pF
C_{oss}	Output Capacitance			--	274	--	
C_{rss}	Reverse Transfer Capacitance			--	222	--	
SWITCHING PARAMETERS							
Q_g(10V)	Total Gate Charge	V_{GS} =10V,V_{DS} =30V, I_D =30A		--	70	--	nC
Q_{gs}	Gate Source Charge			--	20	--	
Q_{gd}	Gate Drain Charge			--	18	--	
$t_{D(on)}$	Turn-On Delay Time	V_{GS} =10V,V_{DS} =30V, I_D =30A, R_G =3Ω		--	15	--	ns
t_r	Turn-On Rise Time			--	94	--	
$T_{D(off)}$	Turn-Off Delay Time			--	46	--	
t_f	Turn-Off Fall Time			--	32	--	
t_{rr}	Body Diode Reverse Recovery Time	I_F =20A, di/dt =100A/μs		--	78	--	ns
Q_{rr}	Body Diode Reverse Recovery Charge			--	51	--	nC

A. Single pulse width limited by maximum junction temperature.

B. The maximum current rating is package limited.

C. The power dissipation P_D is based on $T_{J(MAX)}$ =175ºC, using junction-to-case thermal resistance, and is more useful in setting the upper dissipation limit for cases where additional heatsinking is used.

Typical Characteristics T_J = 25ºC, unless otherwise noted

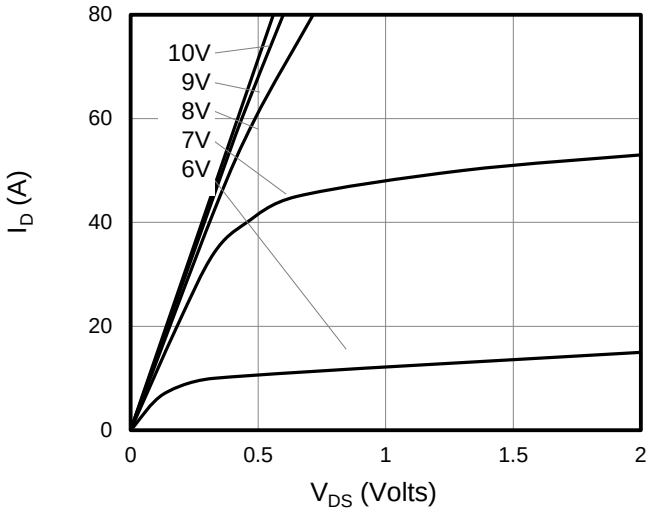


Figure 1: On-Region Characteristics

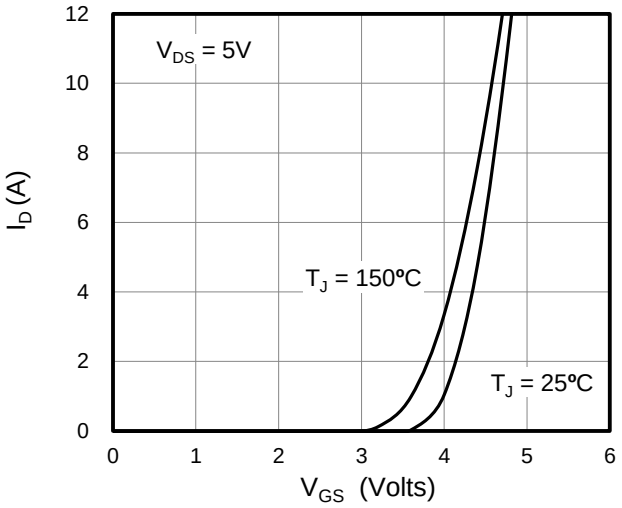


Figure 2: Transfer Characteristics

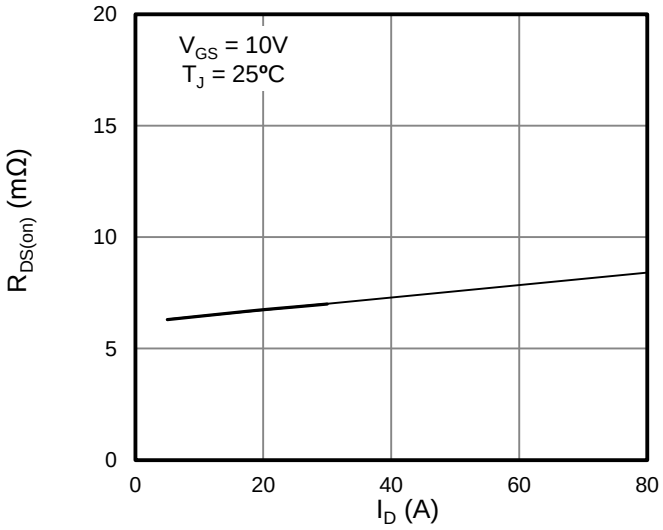


Figure 3: On-Resistance vs. Drain Current

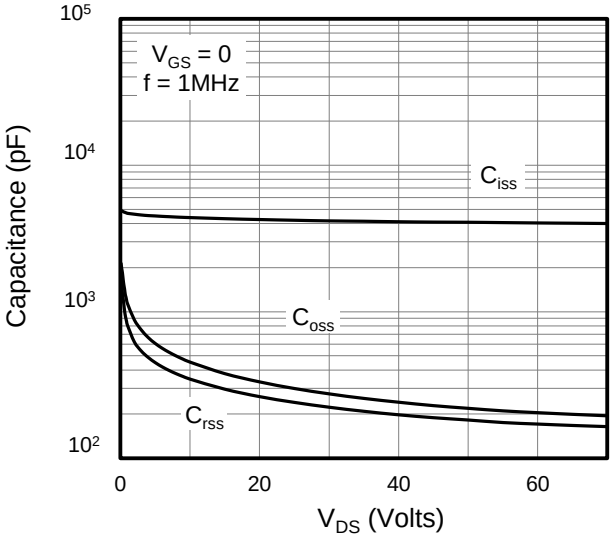


Figure 4: Capacitance Characteristics

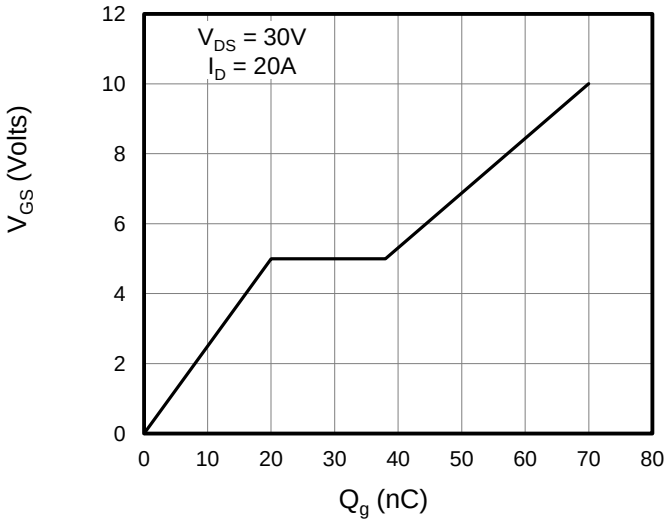


Figure 5: Gate Charge Characteristics

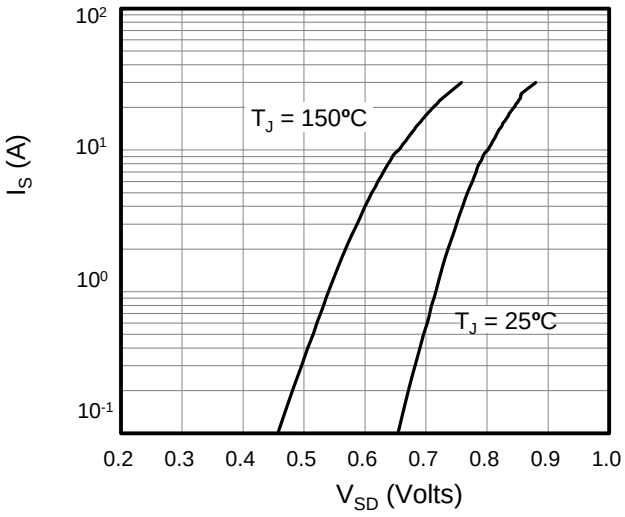


Figure 6: Body Diode Forward Voltage

Typical Characteristics T_J = 25ºC, unless otherwise noted

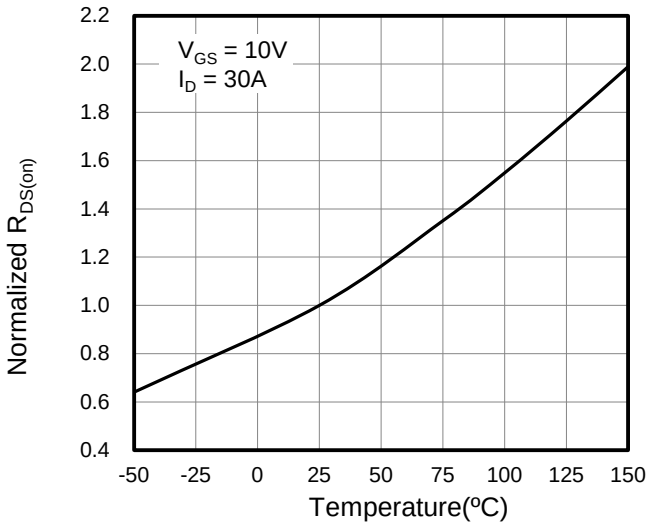


Figure 7: On-Resistance vs. Junction Temperature

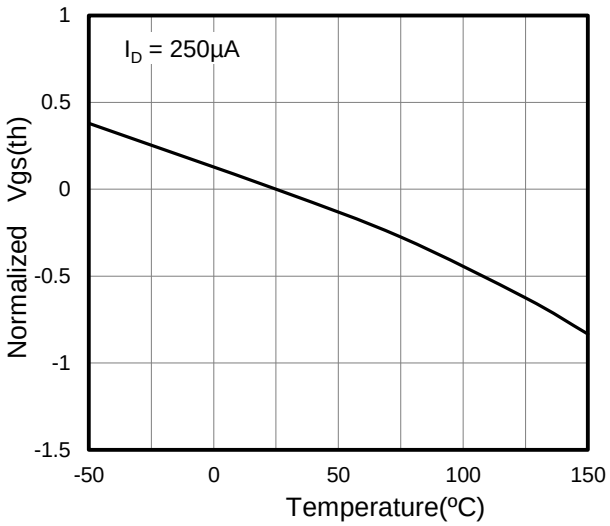


Figure 8: Vgs(th) vs. Junction Temperature

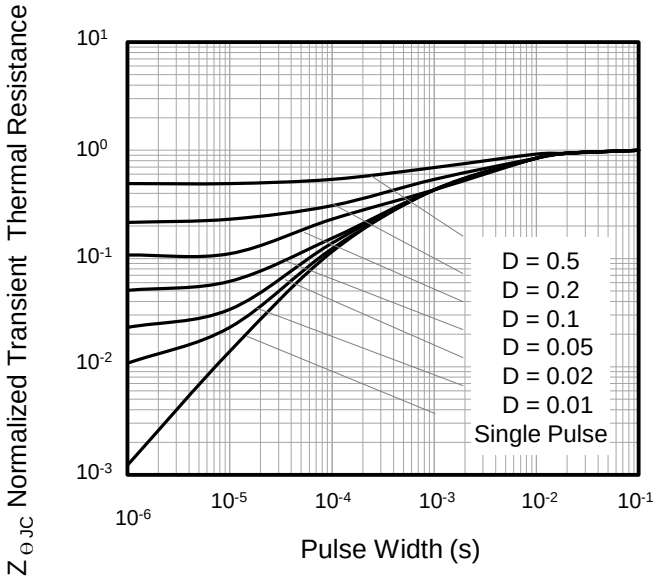


Figure 9: Normalized Transient Thermal Resistance

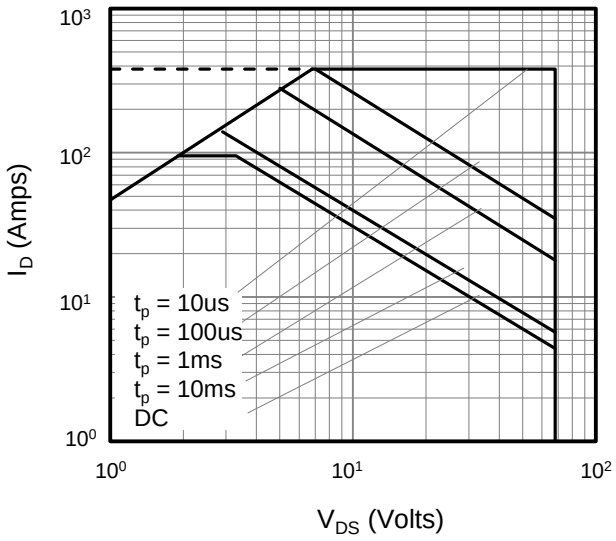


Figure 10: Safe Operating Area

Figure A：Gate Charge Test Circuit and Waveform

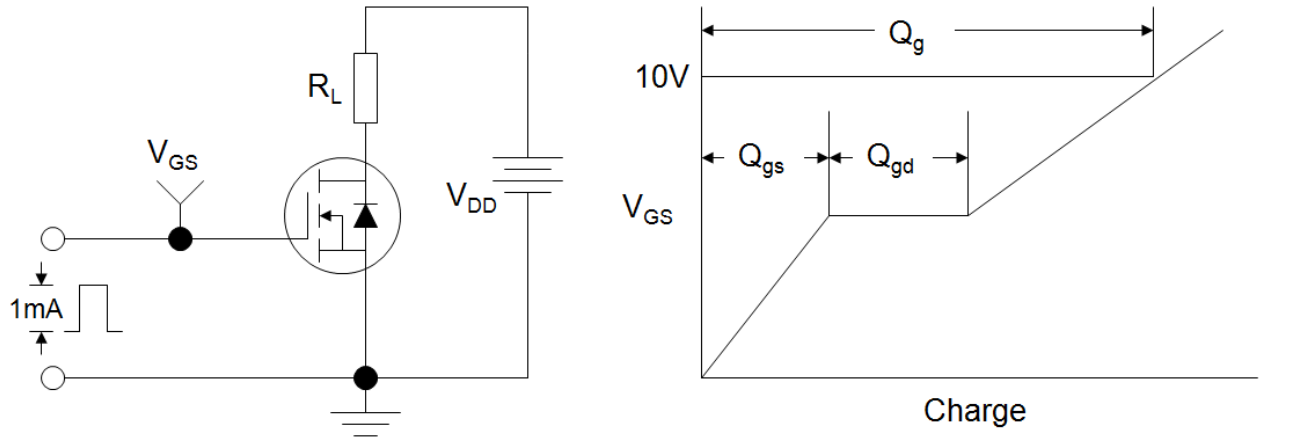


Figure B：Resistive Switching Test Circuit and Waveform

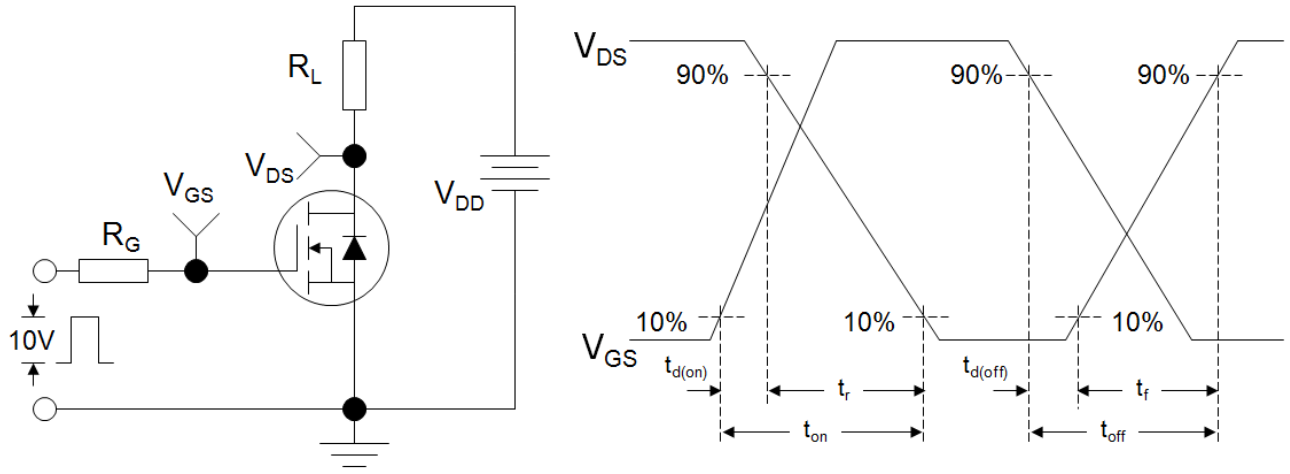
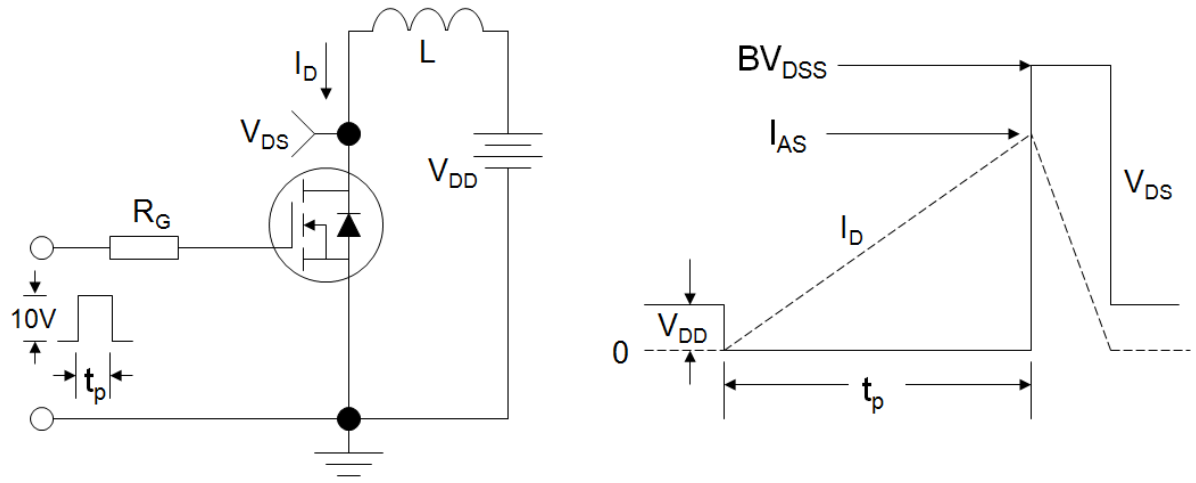
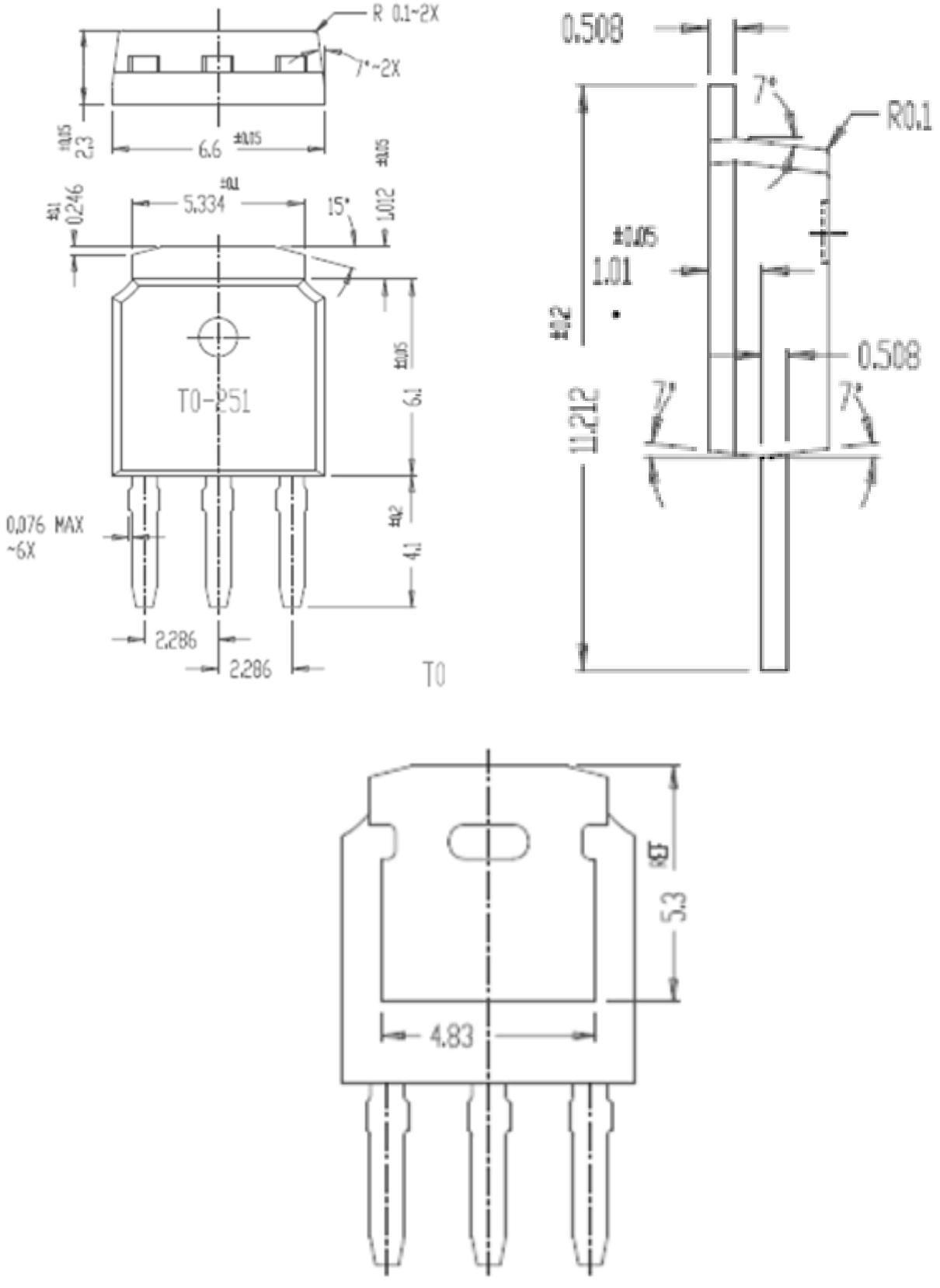


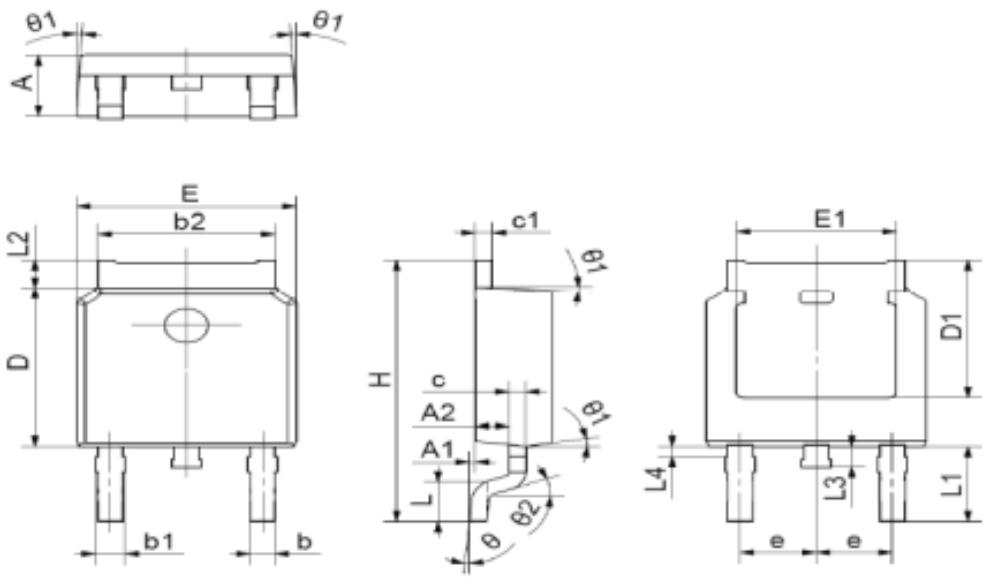
Figure C：Unclamped Inductive Switching Test Circuit and Waveform



TO-251(T)


R 0.1~2X
7°~2X
6.6
5.334
15°
0.246
1.012
2.3
TO-251
6.1
4.1
0.076 MAX
~6X
2.286
2.286
TO
0.508
7°
R0.1
1.01
0.508
11.212
9.7
5.3
4.83

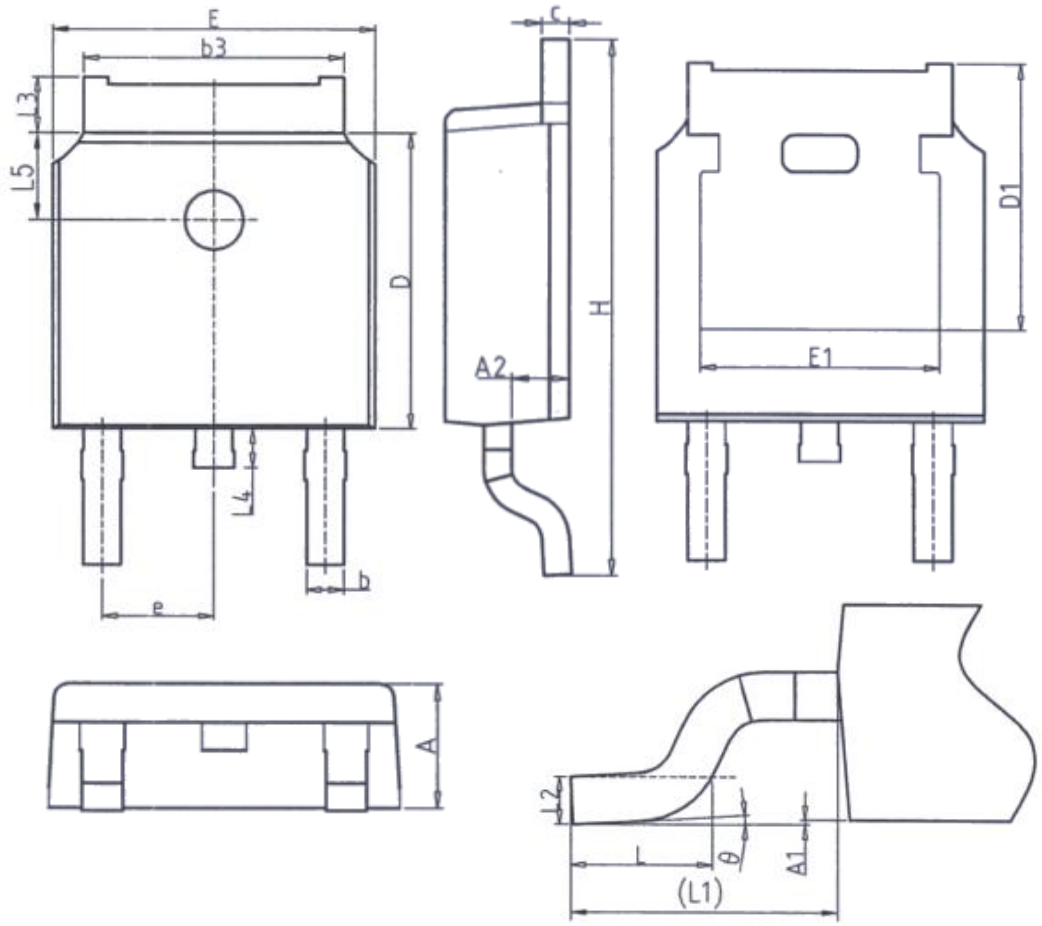
TO-252(E)



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	2.10	2.50	0.083	0.098
A1	0	0.15	0.000	0.006
A2	0.76	1.36	0.030	0.054
b	0.61	0.85	0.024	0.033
b1	0.71	0.91	0.028	0.036
b2	5.04	5.64	0.198	0.222
c	0.508 TYP.		0.02 TYP.	
c1	0.508 TYP.		0.02 TYP.	
D	5.8	6.3	0.228	0.248
D1	5	5.6	0.197	0.220
E	6.3	6.9	0.248	0.272
E1	4.55	5.15	0.179	0.203
e	2.286 TYP.		0.09 TYP.	
H	9.65	10.4	0.380	0.409
L	1.4	1.7	0.055	0.067
L1	2.90 REF.		0.114 REF.	
L2	0.75	1.35	0.030	0.053
L3	0.6	1.2	0.024	0.047
θ	0°	10°	0°	10°
θ1	5°	9°	5°	9°
θ2	25° REF.		25° REF.	

关键尺寸									
A	A1	b	D	E	E1	e	H	D	L1

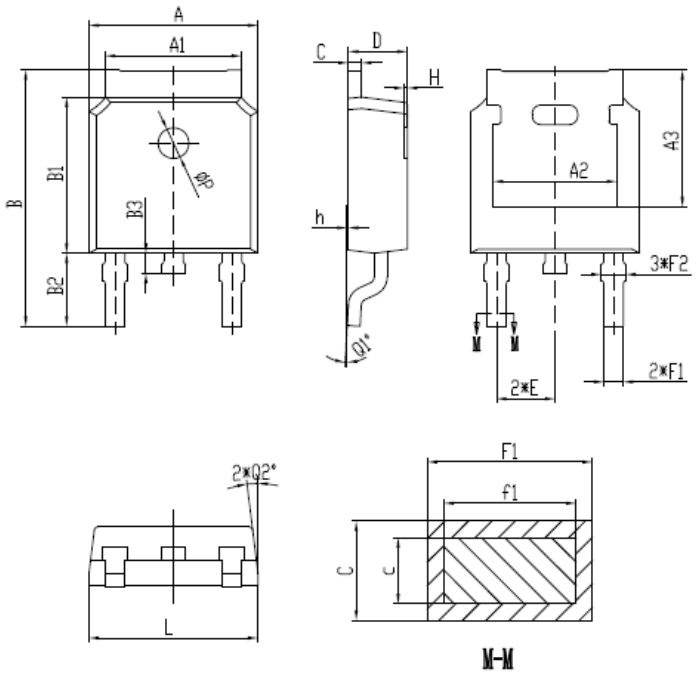
TO-252(H)



Unit: mm		
Symbol	Min.	Max.
A	2.20	2.40
A1	0.00	0.20
A2	0.97	1.17
b	0.68	0.90
b3	5.20	5.50
c	0.43	0.63
D	5.98	6.22
D1	5.30REF	
E	6.40	6.80
E1	4.63	–

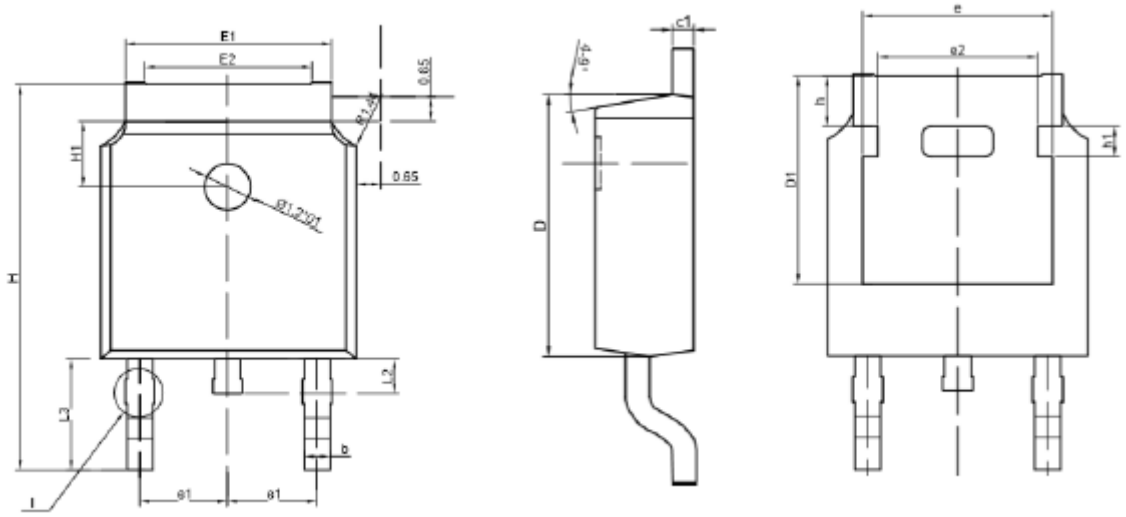
Unit: mm		
Symbol	Min.	Max.
e	2.286BSC	
H	9.40	10.50
L	1.38	1.75
L1	2.90REF	
L2	0.51BSC	
L3	0.88	1.28
L4	–	1.00
L5	1.65	1.95
θ	0°	8°

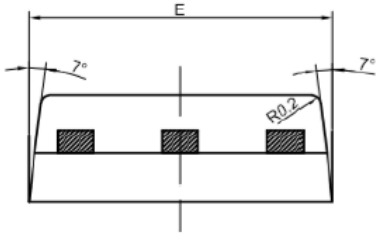
TO-252(T)

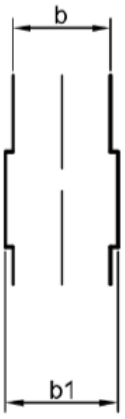


SYMBOL	MIN	NOM	MAX
A	6.50	6.60	6.70
A1	5.16	5.31	5.46
A2		4.83 REF	
A3		5.30 REF	
B	9.77	9.97	10.17
B1	6.00	6.10	6.20
B2	2.60	2.80	3.00
B3	0.70	0.80	0.90
C	0.41	—	0.61
c	0.40	0.50	0.60
D	2.20	2.30	2.40
E	2.186	2.286	2.386
F1	0.67	—	0.87
f1	0.66	0.76	0.86
F2	0.76	0.86	0.96
H	0.00	—	0.30
h	0.00	—	0.20
L	6.50	6.60	6.70
øP	1.10	1.20	1.30
Q1°	0°	—	8°
Q2°	6°	7°	8°

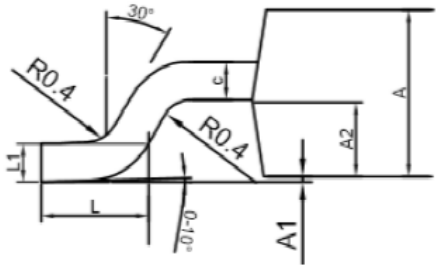
TO-252(Q)







DETAIL I



SYMBOL	MIN	NOM	MAX
A	2.29	2.30	2.31
A1	0.00	0.07	0.15
A2	1.020	1.025	1.030
b	0.645	0.670	0.695
b1	0.67	0.77	0.87
c	0.523	0.528	0.533
c1	0.498	0.508	0.518
D	6.09	6.10	6.11
D1	5.244	5.249	5.254
E	6.50	6.60	6.70
E1	5.284	5.334	5.384
E2	4.284	4.334	4.312
e	4.821	4.826	4.831
e1	2.281	2.286	2.291
e2	4.059	4.064	4.069
H	9.8	10.0	10.2
H1	1.5	1.6	1.7
h	1.316	1.321	1.326
h1	0.757	0.762	0.767
L	1.4	1.5	1.6
L1	0.50	0.51	0.52
L2	0.8	0.9	1.0
L3	2.88	2.888	2.893

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